



Library Indian Institute of Science Education and Research Mohali



DSpace@IISERMohali / Thesis & Dissertation / Master of Science / MS-17

Please use this identifier to cite or link to this item: <http://hdl.handle.net/123456789/4233>

Title:	Graphene josephson junctions and high kinetic inductance aluminum films
Authors:	Bhandari, Parth
Keywords:	Graphene kinetic inductance aluminum films
Issue Date:	Apr-2022
Publisher:	IISER Mohali
Abstract:	<p>Parametric resonance is the phenomenon that occurs due to the presence of non-linear circuit elements. We studied gate tunable graphene-based Josephson junctions (gJJ) and propose a way to observe parametric effects in such devices. We fabricated a gate tunable gJJ by depositing superconducting material on graphene, which was encapsulated by hexagonal boron nitride (hBN). We performed microwave measurements at cryogenic temperature, as our circuit consisted of gJJ embedded on a superconducting cavity formed by the coplanar waveguide (CPW) transmission line. The experiments show that due to the unique electron transport properties of graphene, we can tune the resonator's resonance by applying voltage bias to graphene through DC-line in the cavity. We have studied the temperature and power dependence of quality factor for such resonators. We have discussed the equivalent circuit for the cavity and the junction, and calculated the inductance of the junction. The non-linear circuit element in our case is the gJJ that behaves as a non-linear inductor and when coupled with a cavity can be used to study parametric effects. For the second part of the thesis, we fabricated aluminum thin films to study the grain size of aluminum. Aluminum films were grown in vacuum and under partial pressure of oxygen. The chips were attached to different quartz crystals that were oscillating at different frequencies. The grain size is studied using scanning electron microscopy. It is shown in literature that granular aluminum films have higher kinetic inductance, and the long term goal is to fabricate high kinetic inductance microwave resonators.</p>
URI:	http://hdl.handle.net/123456789/4233
Appears in Collections:	MS-17

Files in This Item:

File	Description	Size	Format	
Yet to obtain consent.pdf		144.56 kB	Adobe PDF	View/Open

Show full item record



Items in DSpace are protected by copyright, with all rights reserved, unless otherwise indicated.